

# Sigurd Wagner

## List of Publications by Citations

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The third column is the impact factor (IF) of the journal, and the fourth column is the number of citations of the article.

164  
papers

6,883  
citations

44  
h-index

81  
g-index

178  
ext. papers

7,384  
ext. citations

3.9  
avg, IF

5.65  
L-index

| #   | Paper   | IF  | Citations |
|-----|---|-----|-----------|
| 164 | Stretchable gold conductors on elastomeric substrates. <i>Applied Physics Letters</i> , <b>2003</b> , 82, 2404-2406   | 3.4 | 733       |
| 163 | Materials for stretchable electronics. <i>MRS Bulletin</i> , <b>2012</b> , 37, 207-213  | 3.2 | 351       |
| 162 | CuInSe <sub>2</sub> /CdS heterojunction photovoltaic detectors. <i>Applied Physics Letters</i> , <b>1974</b> , 25, 434-435  | 3.4 | 327       |
| 161 | Mechanisms of reversible stretchability of thin metal films on elastomeric substrates. <i>Applied Physics Letters</i> , <b>2006</b> , 88, 204103  | 3.4 | 319       |
| 160 | Electronic skin: architecture and components. <i>Physica E: Low-Dimensional Systems and Nanostructures</i> , <b>2004</b> , 25, 326-334  | 3   | 256       |
| 159 | Stretchability of thin metal films on elastomer substrates. <i>Applied Physics Letters</i> , <b>2004</b> , 85, 3435-3437  | 3.4 | 249       |
| 158 | Efficient CuInSe <sub>2</sub> /CdS solar cells. <i>Applied Physics Letters</i> , <b>1975</b> , 27, 89-90  | 3.4 | 242       |
| 157 | Flexible ferroelectret field-effect transistor for large-area sensor skins and microphones. <i>Applied Physics Letters</i> , <b>2006</b> , 89, 073501   | 3.4 | 159       |
| 156 | Flexible active-matrix cells with selectively poled bifunctional polymer-ceramic nanocomposite for pressure and temperature sensing skin. <i>Journal of Applied Physics</i> , <b>2009</b> , 106, 034503 | 2.5 | 157       |
| 155 | Analysis of the electrical and luminescent properties of CuInSe <sub>2</sub> . <i>Journal of Applied Physics</i> , <b>1975</b> , 46, 1777-1782  | 2.5 | 145       |
| 154 | Microfluidic actuation by modulation of surface stresses. <i>Applied Physics Letters</i> , <b>2003</b> , 82, 657-659  | 3.4 | 141       |
| 153 | Compliant thin film patterns of stiff materials as platforms for stretchable electronics. <i>Journal of Materials Research</i> , <b>2005</b> , 20, 3274-3277  | 2.5 | 140       |
| 152 | Stretchable wavy metal interconnects. <i>Journal of Vacuum Science and Technology A: Vacuum, Surfaces and Films</i> , <b>2004</b> , 22, 1723-1725   | 2.9 | 133       |
| 151 | Selective dip-coating of chemically micropatterned surfaces. <i>Journal of Applied Physics</i> , <b>2000</b> , 88, 5119-5126  | 3.6 | 126       |
| 150 | Mechanics of thin-film transistors and solar cells on flexible substrates. <i>Solar Energy</i> , <b>2006</b> , 80, 687-693  | 6.8 | 113       |
| 149 | Capacitive sensing of droplets for microfluidic devices based on thermocapillary actuation. <i>Lab on A Chip</i> , <b>2004</b> , 4, 473-80  | 7.2 | 109       |
| 148 | Morphology of liquid microstructures on chemically patterned surfaces. <i>Journal of Applied Physics</i> , <b>2000</b> , 87, 7768-7775  | 2.5 | 106       |

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| 147 | Effect of contact angle hysteresis on thermocapillary droplet actuation. <i>Journal of Applied Physics</i> , <b>2005</b> , 97, 014906   | 2.5  | 105 |
| 146 | Stiff subcircuit islands of diamondlike carbon for stretchable electronics. <i>Journal of Applied Physics</i> , <b>2006</b> , 100, 014913   | 2.5  | 99  |
| 145 | Titanium dioxide/silicon hole-blocking selective contact to enable double-heterojunction crystalline silicon-based solar cell. <i>Applied Physics Letters</i> , <b>2015</b> , 106, 123906 | 3.4  | 98  |
| 144 | p <sup>+</sup> HP/n <sup>+</sup> Si solar cells and photovoltaic detectors. <i>Applied Physics Letters</i> , <b>1975</b> , 26, 229-230  | 3.4  | 98  |
| 143 | Elastically tunable self-organized organic lasers. <i>Advanced Materials</i> , <b>2011</b> , 23, 869-72   | 2.4  | 94  |
| 142 | Controlling the morphology of gold films on poly(dimethylsiloxane). <i>ACS Applied Materials &amp; Interfaces</i> , <b>2010</b> , 2, 1927-33  | 9.5  | 91  |
| 141 | Silicon for thin-film transistors. <i>Thin Solid Films</i> , <b>2003</b> , 430, 15-19   | 2.2  | 86  |
| 140 | Multicomponent tetrahedral compounds for solar cells. <i>Journal of Crystal Growth</i> , <b>1977</b> , 39, 151-159  | 1.6  | 85  |
| 139 | Hole and electron field-effect mobilities in nanocrystalline silicon deposited at 150 °C. <i>Applied Physics Letters</i> , <b>2002</b> , 80, 440-442                                      | 3.4  | 83  |
| 138 | Using convective flow splitting for the direct printing of fine copper lines. <i>Applied Physics Letters</i> , <b>2000</b> , 77, 2063-2065  | 3.4  | 82  |
| 137 | Green electroluminescence from CdS <sub>0.5</sub> GaS <sub>1.5</sub> heterodiodes. <i>Applied Physics Letters</i> , <b>1973</b> , 22, 351-353   | 3.4  | 77  |
| 136 | A single-layer permeation barrier for organic light-emitting displays. <i>Applied Physics Letters</i> , <b>2008</b> , 92, 103309  | 3.4  | 69  |
| 135 | Diffusion of Boron from Shallow Ion Implants in Silicon. <i>Journal of the Electrochemical Society</i> , <b>1972</b> , 119, 1570  | 3.9  | 66  |
| 134 | Heterojunction band discontinuities. <i>Applied Physics Letters</i> , <b>1976</b> , 28, 31-33   | 3.4  | 65  |
| 133 | Low-Temperature Synthesis of a TiO <sub>2</sub> /Si Heterojunction. <i>Journal of the American Chemical Society</i> , <b>2015</b> , 137, 14842-5  | 16.4 | 59  |
| 132 | ELECTROTEXTILES: CONCEPTS AND CHALLENGES. <i>International Journal of High Speed Electronics and Systems</i> , <b>2002</b> , 12, 391-399  | 0.5  | 59  |
| 131 | Inverter made of complementary p and n channel transistors using a single directly deposited microcrystalline silicon film. <i>Applied Physics Letters</i> , <b>1999</b> , 75, 1125-1127  | 3.4  | 59  |
| 130 | Temperature-dependent nuclear magnetic resonance in CuInX <sub>2</sub> (X=S,Se,Te) chalcopyrite-structure compounds. <i>Physical Review B</i> , <b>1983</b> , 27, 5240-5249               | 3.3  | 59  |

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| 129 | Monitoring hippocampus electrical activity in vitro on an elastically deformable microelectrode array. <i>Journal of Neurotrauma</i> , <b>2009</b> , 26, 1135-45                           | 5.4  | 57 |
| 128 | Highly stable amorphous-silicon thin-film transistors on clear plastic. <i>Applied Physics Letters</i> , <b>2008</b> , 93, 032103  | 3.4  | 57 |
| 127 | Amorphous-Silicon Thin-Film Transistors Fabricated at 300 °C on a Free-Standing Foil Substrate of Clear Plastic. <i>IEEE Electron Device Letters</i> , <b>2007</b> , 28, 1004-1006         | 4.4  | 53 |
| 126 | A comprehensive defect model for amorphous silicon. <i>Journal of Applied Physics</i> , <b>1992</b> , 72, 2857-2872  | 2.5  | 53 |
| 125 | High electron mobility polycrystalline silicon thin-film transistors on steel foil substrates. <i>Applied Physics Letters</i> , <b>1999</b> , 75, 2244-2246                                | 3.4  | 52 |
| 124 | Ultraflexible amorphous silicon transistors made with a resilient insulator. <i>Applied Physics Letters</i> , <b>2010</b> , 96, 042111   | 3.4  | 51 |
| 123 | Preparation and properties of green-light-emitting CdS/CuGaS <sub>2</sub> heterodiodes. <i>Journal of Applied Physics</i> , <b>1974</b> , 45, 246-251                                      | 2.5  | 51 |
| 122 | Physical mechanisms governing pattern fidelity in microscale offset printing. <i>Journal of Applied Physics</i> , <b>2001</b> , 90, 3602-3609  | 2.5  | 50 |
| 121 | Micromechanics of macroelectronics. <i>Particuology: Science and Technology of Particles</i> , <b>2005</b> , 3, 321-328  |      | 44 |
| 120 | Overview of Flexible Electronics Technology. <i>Kluwer International Series in Electronic Materials: Science and Technology</i> , <b>2009</b> , 1-28                                       |      | 40 |
| 119 | Encapsulating Elastically Stretchable Neural Interfaces: Yield, Resolution, and Recording/Stimulation of Neural Activity. <i>Advanced Functional Materials</i> , <b>2012</b> , 22, 640-651 | 15.6 | 39 |
| 118 | Amorphous silicon transistors on ultrathin steel foil substrates. <i>Applied Physics Letters</i> , <b>1999</b> , 74, 2661-2662   |      | 39 |
| 117 | Isotropically stretchable gold conductors on elastomeric substrates. <i>Soft Matter</i> , <b>2011</b> , 7, 7177  | 3.6  | 38 |
| 116 | Evolution of nanocrystalline silicon thin film transistor channel layers. <i>Journal of Non-Crystalline Solids</i> , <b>2004</b> , 338-340, 720-724  | 3.9  | 38 |
| 115 | Mechanics of TFT Technology on Flexible Substrates <b>2005</b> , 263-283   |      | 38 |
| 114 | Enabling Scalable Hybrid Systems: Architectures for Exploiting Large-Area Electronics in Applications. <i>Proceedings of the IEEE</i> , <b>2015</b> , 103, 690-712                         | 14.3 | 36 |
| 113 | Motion of p-n junctions in CuInSe <sub>2</sub> . <i>Applied Physics Letters</i> , <b>1976</b> , 28, 454-455  | 3.4  | 35 |
| 112 | Preparation and properties of InP/CdS solar cells. <i>Journal of Applied Physics</i> , <b>1976</b> , 47, 614-618   | 2.5  | 35 |

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|-----|---|-----|----|
| 111 | Amorphous silicon thin-film transistors with field-effect mobilities of 2 cm <sup>2</sup> /V s for electrons and 0.1 cm <sup>2</sup> /V s for holes. <i>Applied Physics Letters</i> , <b>2009</b> , 94, 162105  | 3.4 | 30 |
| 110 | Reliability of Active-Matrix Organic Light-Emitting-Diode Arrays With Amorphous Silicon Thin-Film Transistor Backplanes on Clear Plastic. <i>IEEE Electron Device Letters</i> , <b>2008</b> , 29, 63-66   | 4.4 | 28 |
| 109 | Innovation highway: Breakthrough milestones and key developments in chalcopyrite photovoltaics from a retrospective viewpoint. <i>Thin Solid Films</i> , <b>2017</b> , 633, 2-12  | 2.2 | 26 |
| 108 | Tradeoff regimes of lifetime in amorphous silicon thin-film transistors and a universal lifetime comparison framework. <i>Applied Physics Letters</i> , <b>2009</b> , 95, 143504  | 3.4 | 26 |
| 107 | Modeling the electrical resistance of gold film conductors on uniaxially stretched elastomeric substrates. <i>Applied Physics Letters</i> , <b>2011</b> , 98, 212112  | 3.4 | 26 |
| 106 | Fast growth of hydrogenated amorphous silicon from dichlorosilane. <i>Applied Physics Letters</i> , <b>1994</b> , 65, 1940-1942   | 3.4 | 25 |
| 105 | Topographies of plasma-hardened surfaces of poly(dimethylsiloxane). <i>Journal of Applied Physics</i> , <b>2010</b> , 108, 093522   | 2.5 | 23 |
| 104 | Thermomechanical criteria for overlay alignment in flexible thin-film electronic circuits. <i>Applied Physics Letters</i> , <b>2006</b> , 88, 011905  | 3.4 | 22 |
| 103 | Alterations in Hippocampal Network Activity after In Vitro Traumatic Brain Injury. <i>Journal of Neurotrauma</i> , <b>2015</b> , 32, 1011-9   | 5.4 | 21 |
| 102 | Direct printing of polymer microstructures on flat and spherical surfaces using a letterpress technique. <i>Journal of Vacuum Science &amp; Technology an Official Journal of the American Vacuum Society B, Microelectronics Processing and Phenomena</i> , <b>2002</b> , 20, 2320 |     | 21 |
| 101 | Chemistry and preparation of InP/CdS solar cells. <i>Journal of Crystal Growth</i> , <b>1977</b> , 39, 128-136  | 1.6 | 20 |
| 100 | Large-Area Resistive Strain Sensing Sheet for Structural Health Monitoring. <i>Sensors</i> , <b>2020</b> , 20,  | 3.8 | 18 |
| 99  | Amorphous silicon: Vehicle and test bed for large-area electronics. <i>Physica Status Solidi (A) Applications and Materials Science</i> , <b>2010</b> , 207, 501-509  | 1.6 | 18 |
| 98  | Generation of high-resolution surface temperature distributions. <i>Journal of Applied Physics</i> , <b>2002</b> , 91, 5686-5693  | 2.5 | 18 |
| 97  | . <i>IEEE Transactions on Electron Devices</i> , <b>2010</b> , 57, 2381-2389  | 2.9 | 17 |
| 96  | Effect of $\text{SiN}_x$ Gate Dielectric Deposition Power and Temperature on a-Si:H TFT Stability. <i>IEEE Electron Device Letters</i> , <b>2007</b> , 28, 606-608  | 4.4 | 17 |
| 95  | Microfluidic detection and analysis by integration of thermocapillary actuation with a thin-film optical waveguide. <i>Applied Physics Letters</i> , <b>2005</b> , 86, 184101   | 3.4 | 17 |
| 94  | n-CdS/n-GaAs voltage-enhanced photoanode. <i>Applied Physics Letters</i> , <b>1977</b> , 31, 446-447  | 3.4 | 17 |

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|----|---|-----|----|
| 93 | Thin-film circuits for scalable interfacing between large-area electronics and CMOS ICs <b>2014</b> ,   |     | 16 |
| 92 | Plastic Deformation of Thin Foil Substrates with Amorphous Silicon Islands into Spherical Shapes. <i>Materials Research Society Symposia Proceedings</i> , <b>2000</b> , 621, 861                               |     | 15 |
| 91 | Diffusion of atmospheric gases into barrier-layer sealed organic light emitting diodes. <i>Applied Physics Letters</i> , <b>2008</b> , 93, 203306   | 3.4 | 14 |
| 90 | High hole and electron field effect mobilities in nanocrystalline silicon deposited at 150 °C. <i>Thin Solid Films</i> , <b>2003</b> , 427, 56-59   | 2.2 | 13 |
| 89 | . <i>Journal of Display Technology</i> , <b>2007</b> , 3, 304-308   |     | 12 |
| 88 | Incorporation of a light and carrier collection management nano-element array into superstrate a-Si:H solar cells. <i>Applied Physics Letters</i> , <b>2011</b> , 99, 073113                                    | 3.4 | 11 |
| 87 | Fabricating Metal Interconnects for Circuits on a Spherical Dome. <i>Journal of the Electrochemical Society</i> , <b>2006</b> , 153, G259   | 3.9 | 11 |
| 86 | Super-elastic Gold Conductors on Elastomeric Substrates. <i>Materials Research Society Symposia Proceedings</i> , <b>2003</b> , 769, 1031   |     | 11 |
| 85 | Amorphous silicon thin-film transistors with DC saturation current half-life of more than 100 years <b>2008</b> ,   |     | 10 |
| 84 | Integrating and Interfacing Flexible Electronics in Hybrid Large-Area Systems. <i>IEEE Transactions on Components, Packaging and Manufacturing Technology</i> , <b>2015</b> , 5, 1219-1229                      | 1.7 | 9  |
| 83 | Nonvolatile Amorphous-Silicon Thin-Film-Transistor Memory Structure for Drain-Voltage Independent Saturation Current. <i>IEEE Transactions on Electron Devices</i> , <b>2011</b> , 58, 2924-2927                | 2.9 | 9  |
| 82 | <b>2012</b> ,   |     | 9  |
| 81 | . <i>IEEE Transactions on Electron Devices</i> , <b>2008</b> , 55, 973-977  | 2.9 | 9  |
| 80 | Impact of bending on flexible metal oxide TFTs and oscillator circuits. <i>Journal of the Society for Information Display</i> , <b>2016</b> , 24, 371-380   | 2.1 | 9  |
| 79 | Top-Gate Amorphous Silicon TFT With Self-Aligned Silicide Source/Drain and High Mobility. <i>IEEE Electron Device Letters</i> , <b>2008</b> , 29, 737-739   | 4.4 | 8  |
| 78 | A Method for Making Elastic Metal Interconnects. <i>Materials Research Society Symposia Proceedings</i> , <b>2003</b> , 769, 6121   |     | 8  |
| 77 | The Distribution of Occupied Deep Levels in a-Si:H Determined from CPM Spectra. <i>Materials Research Society Symposia Proceedings</i> , <b>1991</b> , 219, 611   |     | 8  |
| 76 | 18-2: Oxide TFT LC Oscillators on Glass and Plastic for Wireless Functions in Large-Area Flexible Electronic Systems. <i>Digest of Technical Papers SID International Symposium</i> , <b>2016</b> , 47, 207-210 | 0.5 | 7  |

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|----|--|------|---|
| 75 | A New Gate Dielectric for Highly Stable Amorphous-Silicon Thin-Film Transistors With $\sim 1.5\text{-cm}^2/\text{V}\cdot\text{s}$ Electron Field-Effect Mobility. <i>IEEE Electron Device Letters</i> , <b>2009</b> , 30, 502-504  | 4.4  | 7 |
| 74 | Stretchable microelectrode arrays—a tool for discovering mechanisms of functional deficits underlying traumatic brain injury and interfacing neurons with neuroprosthetics. <i>Annual International Conference of the IEEE Engineering in Medicine and Biology Society</i> , <b>2006</b> , Suppl, 6732-5 |      | 7 |
| 73 | How Stretchable Can We Make Thin Metal Films?. <i>Materials Research Society Symposia Proceedings</i> , <b>2005</b> , 875, 1   |      | 7 |
| 72 | Effects of Deposition Temperature and Film Thickness on the Structural, Electrical, and Optical Properties of Germanium Thin Films. <i>Materials Research Society Symposia Proceedings</i> , <b>2002</b> , 715, 1821   |      | 7 |
| 71 | Amorphous Silicon Thin Film Transistors on Kapton Fibers. <i>Materials Research Society Symposia Proceedings</i> , <b>2002</b> , 736, 1  |      | 7 |
| 70 | Deformable interconnects for conformal integrated circuits. <i>Materials Research Society Symposia Proceedings</i> , <b>2002</b> , 736, 1  |      | 7 |
| 69 | Epitaxy in solar cells. <i>Journal of Crystal Growth</i> , <b>1975</b> , 31, 113-121   | 1.6  | 7 |
| 68 | Thin-film semiconductors—from exploration to application. <i>MRS Bulletin</i> , <b>2018</b> , 43, 617-624  | 3.2  | 6 |
| 67 | Hybrid Amorphous/Nanocrystalline Silicon Schottky Diodes for High Frequency Rectification. <i>IEEE Electron Device Letters</i> , <b>2014</b> , 35, 425-427   | 4.4  | 6 |
| 66 | Stability of Amorphous Silicon Thin Film Transistors under Prolonged High Compressive Strain. <i>Materials Research Society Symposia Proceedings</i> , <b>2007</b> , 989, 4  |      | 6 |
| 65 | Stretchable conductors: thin gold films on silicone elastomer. <i>Materials Research Society Symposia Proceedings</i> , <b>2003</b> , 795, 415   |      | 6 |
| 64 | Photoresist-free printing of amorphous silicon thin-film transistors. <i>Applied Physics Letters</i> , <b>2003</b> , 83, 3207-3209   | 3.4  | 6 |
| 63 | Thin Film Transistors Made of Polysilicon Crystallized at 950°C on Steel Substrate. <i>Materials Research Society Symposia Proceedings</i> , <b>2000</b> , 609, 2851   |      | 6 |
| 62 | The effect of chlorine on dopant activation in hydrogenated amorphous silicon. <i>Applied Physics Letters</i> , <b>2000</b> , 76, 2949-2951  | 3.4  | 6 |
| 61 | Kinetics of Growth and Recovery of Light-Induced Defects Under High-Intensity Illumination. <i>Materials Research Society Symposia Proceedings</i> , <b>1992</b> , 258, 473  |      | 6 |
| 60 | Wireless biomechanical power harvesting via flexible magnetostrictive ribbons. <i>Energy and Environmental Science</i> , <b>2014</b> , 7, 2243   | 35.4 | 5 |
| 59 | A System Based on Capacitive Interfacing of CMOS With Post-Processed Thin-Film MEMS Resonators Employing Synchronous Readout for Parasitic Nulling. <i>IEEE Journal of Solid-State Circuits</i> , <b>2015</b> , 50, 1002-1015  | 5.5  | 5 |
| 58 | Self-Aligned Top-Gate Coplanar a-Si:H Thin-Film Transistors With a $\text{SiO}_2/\text{Si}$ Hybrid Gate Dielectric. <i>IEEE Electron Device Letters</i> , <b>2011</b> , 32, 36-38  | 4.4  | 5 |

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| 57 | ELASTOMERIC INTERCONNECTS. <i>International Journal of High Speed Electronics and Systems</i> , <b>2006</b> , 16, 397-407  | 0.5 | 5 |
| 56 | P-24: High-Temperature (250°C) Amorphous-Silicon TFTs On Clear Plastic Substrates. <i>Digest of Technical Papers SID International Symposium</i> , <b>2005</b> , 36, 313   | 0.5 | 5 |
| 55 | Thermal oxide of polycrystalline silicon on steel foil as a thin-film transistor gate dielectric. <i>Applied Physics Letters</i> , <b>2001</b> , 78, 3729-3731   | 3.4 | 5 |
| 54 | High Electron Mobility TFTs of Nanocrystalline Silicon Deposited at 150°C on Plastic Foil. <i>Materials Research Society Symposia Proceedings</i> , <b>2001</b> , 664, 2611  |     | 5 |
| 53 | Large-Area Electronics HF RFID Reader Array for Object-Detecting Smart Surfaces. <i>IEEE Solid-State Circuits Letters</i> , <b>2018</b> , 1, 182-185   | 2   | 5 |
| 52 | Self-aligned ZnO thin-film transistors with 860 MHz fT and 2 GHz fmax for large-area applications <b>2017</b> ,  |     | 4 |
| 51 | Electrical Properties of Phosphorus-Doped and Boron-Doped Nanocrystalline Germanium Thin-Films for p-i-n Devices. <i>Materials Research Society Symposia Proceedings</i> , <b>2003</b> , 762, 571  |     | 4 |
| 50 | An Inverter Woven from Flat Component Fibers for e-Textile Applications. <i>Materials Research Society Symposia Proceedings</i> , <b>2003</b> , 769, 9101  |     | 4 |
| 49 | Thermocapillary Actuation of Liquids Using Patterned Microheater Arrays. <i>Materials Research Society Symposia Proceedings</i> , <b>2003</b> , 773, 1031  |     | 4 |
| 48 | Monolithically Integrated p- & n- Channel Thin Film Transistors of Nanocrystalline Silicon on Plastic Substrates. <i>Materials Research Society Symposia Proceedings</i> , <b>2004</b> , 808, 281  |     | 4 |
| 47 | Amorphous silicon crystallization and polysilicon thin film transistors on SiO <sub>2</sub> passivated steel foil substrates. <i>Applied Surface Science</i> , <b>2001</b> , 175-176, 753-758  | 6.7 | 4 |
| 46 | Mechanical Theory of the Film-on-Substrate-Foil Structure: Curvature and Overlay Alignment in Amorphous Silicon Thin-Film Devices Fabricated on Free-Standing Foil Substrates. <i>Kluwer International Series in Electronic Materials: Science and Technology</i> , <b>2009</b> , 29-51    |     | 4 |
| 45 | Current gain of amorphous silicon thin-film transistors above the cutoff frequency <b>2014</b> ,   |     | 3 |
| 44 | 65.1: Invited Paper: Amorphous Silicon TFTs with 100-Year Lifetimes in a Clear Plastic Compatible Process for AMOLEDs. <i>Digest of Technical Papers SID International Symposium</i> , <b>2009</b> , 40, 979   | 0.5 | 3 |
| 43 | Thin Film Transistors with Electron Mobility of 40 cm <sup>2</sup> V <sup>-1</sup> s <sup>-1</sup> Made from Directly Deposited Intrinsic Microcrystalline Silicon. <i>Materials Research Society Symposia Proceedings</i> , <b>2000</b> , 609, 3121                                       |     | 3 |
| 42 | Electroluminescent p-InP/n-CdS heterodiodes. <i>Applied Physics Letters</i> , <b>1976</b> , 29, 431-432  | 3.4 | 3 |
| 41 | Stretchable Neural Interfaces <b>2012</b> , 379-399  |     | 2 |
| 40 | Neural sensing of electrical activity with stretchable microelectrode arrays. <i>Annual International Conference of the IEEE Engineering in Medicine and Biology Society IEEE Engineering in Medicine and Biology Society Annual International Conference</i> , <b>2009</b> , 2009, 4210-3 | 0.9 | 2 |



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|----|--|-----|---|
| 39 | SiNx barrier layers deposited at 250°C on a clear polymer substrate. <i>Materials Research Society Symposia Proceedings</i> , <b>2006</b> , 936, 1   |     | 2 |
| 38 | Stretchable Dielectric Material for Conformable Bioelectronic Devices. <i>Materials Research Society Symposia Proceedings</i> , <b>2006</b> , 926, 1   |     | 2 |
| 37 | Material Characterisation of a Novel Permeation Barrier for Flexible Organic Displays. <i>Materials Research Society Symposia Proceedings</i> , <b>2007</b> , 1007, 1  |     | 2 |
| 36 | 64.3: Amorphous Silicon Thin-Film Transistor Backplane on Stainless Steel Foil Substrates for AMOLEDs. <i>Digest of Technical Papers SID International Symposium</i> , <b>2006</b> , 37, 1862  | 0.5 | 2 |
| 35 | Structural Evolution of Nanocrystalline Germanium Thin Films with Film Thickness and Substrate Temperature. <i>Materials Research Society Symposia Proceedings</i> , <b>2003</b> , 762, 651  |     | 2 |
| 34 | Hydrogen in Ultralow Temperature SiO <sub>2</sub> for Nanocrystalline Silicon Thin Film Transistors. <i>Materials Research Society Symposia Proceedings</i> , <b>2004</b> , 814, 30  |     | 2 |
| 33 | Spatially selective single-grain silicon films induced by hydrogen plasma seeding. <i>Journal of Vacuum Science &amp; Technology an Official Journal of the American Vacuum Society B, Microelectronics Processing and Phenomena</i> , <b>2002</b> , 20, 818 |     | 2 |
| 32 | Offset Printing of Liquid Microstructures for High Resolution Lithography. <i>Materials Research Society Symposia Proceedings</i> , <b>2000</b> , 624, 47  |     | 2 |
| 31 | P-channel Polycrystalline Silicon Thin Film Transistors on Steel Foil Substrates. <i>Materials Research Society Symposia Proceedings</i> , <b>2001</b> , 664, 1721   |     | 2 |
| 30 | Nanocrystalline Silicon TFTs With 50 nm Thick Deposited Channel Layer, 10 cm <sup>2</sup> /Vs Electron Mobility and 108 On/Off Current Ratio. <i>Materials Research Society Symposia Proceedings</i> , <b>2001</b> , 664, 1751                               |     | 2 |
| 29 | Physico-Chemical Problems in Photovoltaic Research. <i>Zeitschrift Fur Elektrotechnik Und Elektrochemie</i> , <b>1980</b> , 84, 991-995  |     | 2 |
| 28 | A symmetrical stretching stage for electrical atomic force microscopy. <i>Measurement: Journal of the International Measurement Confederation</i> , <b>2016</b> , 87, 185-188  | 4.6 | 2 |
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